LN175 GaAlAs Infrared Light Emitting Diode

For optical control systems

Features

- High-power output, high-efficiency: $P_0 = 12 \text{ mW} \text{ (typ.)}$
- Emitted light spectrum suited for silicon photodetectors: $\lambda_P = 900 \text{ nm}$ (typ.)
- Good radiant power output linearity with respect to input current
- Wide directivity: $\theta = 120^{\circ}$ (typ.)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Power dissipation	P _D	170	mW	
Forward current	I _F	100	mA	
Pulse forward current *	I _{FP}	2	А	
Reverse voltage	V _R	3	V	
Operating ambient temperature	T _{opr}	-25 to +85	°C	
Storage temperature	T _{stg}	-40 to +100	°C	

Note) *: f = 100 Hz, Duty cycle = 0.1%

Electro-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Radiant power *	Po	$I_{\rm F} = 100 \mathrm{mA}$	7.0	12.0	96.	mW
Reverse current	I _R	$V_R = 3 V$		CO.	10	μΑ
Forward voltage	V _F	$I_{\rm F} = 100 \mathrm{mA}$	ON C	1.4	1.7	V
Terminal capacitance	Ct	$V_{\rm R} = 0 \text{V}, \text{f} = 1 \text{MHz}$		50		pF
Peak emission wavelength	$\lambda_{\rm P}$	I _F = 100 mA	$\mathcal{S}_{\mathcal{O}}$	900		nm
Spectral half band width	Δλ	$I_{\rm F} = 100 {\rm mA}$		70		nm
Rise time	t _r	I _{FP} = 100 mA		700		ns
Fall time	t _f	$I_{\rm FP} = 100 \mathrm{mA}$		700		ns
Half-power angle	θ	The angle when the radiant power is halved.		120		0

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

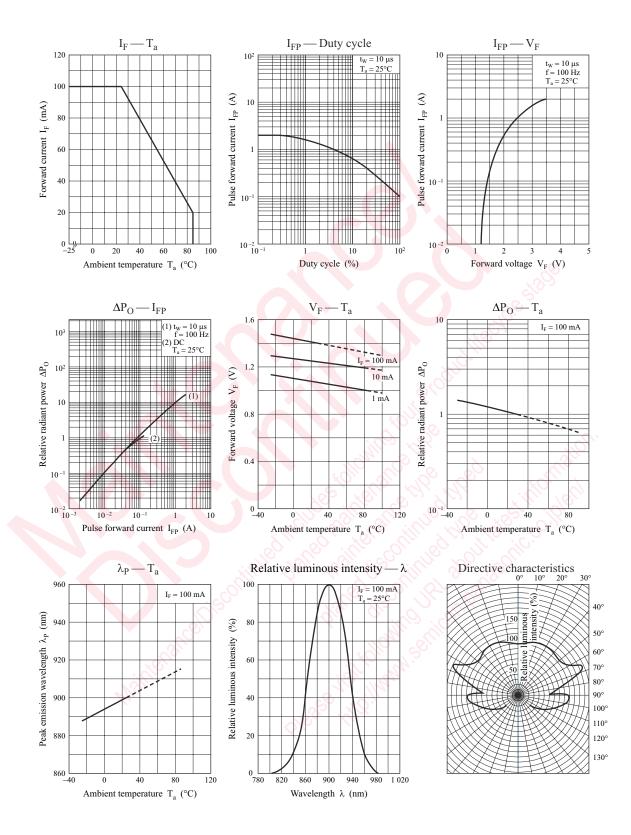
2. Cutoff frequency: 0.55 MHz

$$f_{\rm C}: 10 \times \log \frac{P_{\rm O} \text{ at } f = f_{\rm C}}{P_{\rm O} \text{ at } f = 1 \text{ MHz}} = -3$$

3. *: A light detection element uses a silicon diode have proofread a load with a standard device.

LN175

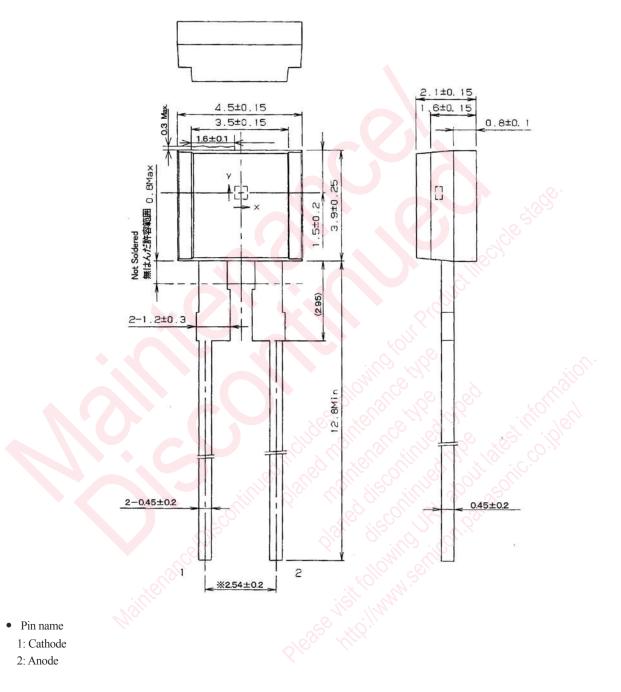
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Package (Unit: mm)





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